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Front Matter: Volume 10365

, "Front Matter: Volume 10365," Proc. SPIE 10365, Organic Field-Effect Transistors XVI, 1036501 (2 November 2017); doi: 10.1117/12.2297124

SPIE.

Event: SPIE Organic Photonics + Electronics, 2017, San Diego, California, United States

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Organic Field-Effect Transistors XVI

Iain McCulloch
Oana D. Jurchescu
Editors

7–9 August 2017
San Diego, California, United States

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Volume 10365

Proceedings of SPIE 0277-786X, V. 10365

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Organic Field-Effect Transistors XVI, edited by Iain McCulloch, Oana D. Jurchescu,
Proc. of SPIE Vol. 10365, 1036501 · © 2017 SPIE · CCC code: 0277-786X/17/\$18
doi: 10.1117/12.2297124

Proc. of SPIE Vol. 10365 1036501-1

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Author(s), "Title of Paper," in *Organic Field-Effect Transistors XVI*, edited by Iain McCulloch, Oana D. Jurchescu, Proceedings of SPIE Vol. 10365 (SPIE, Bellingham, WA, 2017) Seven-digit Article CID Number.

ISSN: 0277-786X
ISSN: 1996-756X (electronic)

ISBN: 9781510611870
ISBN: 9781510611887 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
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